SUPPLEMENTARY INFORMATION

Strongly reduced lattice thermal conductivity in Sn-doped rare-earth (M) filled skutterudites M_xCo₄Sb_{12-y}Sn_y, promoted by Sb-Sn disordering and phase segregation

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Figure S1. Laboratory XRD patterns of as-grown $Ce_{0.5}Co_4Sb_{12-y}Sb_y$ (y = 0.2, 0.4, 1.0) at room temperature. The star corresponds to the most intense reflection of Sb impurity.



Figure S2. Observed (red crosses), calculated (black full line) and their difference (blue line), SXRD profiles for $Ce_{0.5}Co_4Sb_{12-y}Sn_y$ (y = 0.2, 1) at 295 K, with the peak splitting highlighted in the Insets. For x = 0.2, the two series of Bragg reflections correspond to the two coexistent skutterudite phases.





Figure S3. Observed (red crosses), calculated (black full line) and their difference (blue line), SXRD profiles for $Ce_{0.5}Co_4Sb_{11.6}Sn_{0.4}$ at 200, 400, 600 and 800°C.The two series of Bragg reflections correspond to the two coexistent skutterudite phases. At 800°C, the incipient decomposition of the skutterudite phase is observed.





Figure S4. Observed (red crosses), calculated (black full line) and their difference (blue line), SXRD profiles for $La_{0.5}Co_4Sb_{11.6}Sn_{0.4}$ at 200, 400, 600 and 800°C. The two series of Bragg reflections correspond to the two coexistent skutterudite phases. At 800°C, the incipient decomposition of the skutterudite phase is observed.





Figure S5. Observed (red crosses), calculated (black full line) and their difference (blue line), SXRD profiles for $Yb_{0.5}Co_4Sb_{11.6}Sn_{0.4}$ at 200, 400, 600 and 800°C.The two series of Bragg reflections correspond to the two coexistent skutterudite phases. At 800°C, the incipient decomposition of the skutterudite phase is observed.

Nominal Composition	$Ce_{0.5}Co_4Sb_{11.8}Sn_{0.2}$		Ce _{0.5} Co ₄ Sb ₁₁₋₀ Sn _{1.0}
Refined Composition	$Ce_{0.07}Co_4Sb_{11.8}Sn_{0.2}$	$Ce_{0.17}Co_4Sb_{11.8}Sn_{0.2}$	$Ce_{0.16}Co_4Sb_{11.0}Sn_{1.0}$
Phase abundance (%)	77.6(3)	22.4(2)	100%
Lattice parameter (å)	9.04203(3)	9.05289(4)	9.04933(2)
Volume (Å ³)	739.260(4)	741.928(6)	741.05(1)
U ₁₁ (Co) / Å ² *	0.0052(3)		0.0050(3)
U ₁₂ (Co) / Å ² **	0.0000(4)		0.0004(5)
y (Sb)	0.33506(6)	0.3354(2)	0.33523(7)
z (Sb)	0.15793(6)	0.1591(2)	0.15827(7)
Occ. R (<1)	0.065(3)	0.17(1)	0.157(5)
U ₁₁ (Sb) / Å ² ***	0.0070(3)		0.0074(3)
U ₂₂ (Sb) / Å ²	0.0118(4)		0.0109(4)
U ₃₃ (Sb) / Å ²	0.0087(4)		0.0081(4)
U ₂₃ (Sb) / Å ²	0.0006(2)		0.0011(3)
U ₁₁ (R) / Å ² ****	0.031(6)		0.054(7)
d Co-Sb (å)	2.5287(3)	2.5292(7)	2.5302(3)
d ₁ Sb-Sb (å)	2.8560(9)	2.881(2)	2.8645(9)
d ₂ Sb-Sb (å)	2.9828(9)	2.980(2)	2.9821(9)
R _p (%)	5.98		10.584
R _{wp} (%)	7.67		18.623
R _{exp} (%)	4.08		5.942
R _{Bragg} (%)	1.36	2.99	1.937
χ²(%)	3.54		4.15
Sb at 24g, $(0,y,z)$; Co at 8c $(\frac{1}{4},\frac{1}{4},\frac{1}{4})$; R at 2a $(0,0,0)$			

Table S1. Refined structural parameters of $Ce_{0.5}Co_4Sb_{12-y}Sn_y$ (y = 0.2, 1.0) at room temperaturefrom SXRD data. Space group: Im^3 .

Sb at 24g, (0,y,z); Co at 8c $(\frac{1}{4},\frac{1}{4},\frac{1}{4})$; R at 2a (0,0,0)Anisotropic U Co: * U₁₁ = U₂₂ = U₃₃; ** U₁₂ = U₂₃ = U₁₃; Sb: *** U₁₂ = U₁₃ = 0; R: ****U₁₁ = U₂₂ = U₃₃ **Table S2.** Estimated carrier density calculated for each composition, using the Single Parabolic Band approximation, from the measured Seebeck coefficient. These values are not obtained from Hall effect measurements, but from the experimental Seebeck coefficient.

Composition	Carrier density (10 ²⁰ cm ⁻³)
$La_{0.5}Co_4Sb_{11.6}Sn_{0.4}$	2.13 - 2.57
Ce _{0.5} Co ₄ Sb _{11.6} Sn _{0.4}	1.98 – 2.39
Yb _{0.5} Co ₄ Sb _{11.6} Sn _{0.4}	1.77 – 2.14
$La_{0.5}Co_4Sb_{12}$	6.07 - 7.33
$Ce_{0.5}Co_4Sb_{12}$	0.62 - 0.74
$Yb_{0.5}Co_4Sb_{12}$	1.77 – 2.14

We have considered two different effective masses in the calculation, $1.5m_e$ and $1.7m_e$, common reported values in skutterudites.

Table S3. Refinement of the La occupancy factors from the SXRD data at different temperatures. To create this table, we have repeated the Rietveld refinements with released occupancy factor of the filler in the $La_{0.5}Co_4Sb_{11.6}Sn_{0.4}$ compound, although the occupancy factor and the displacement parameters are strongly related, making this analysis difficult.

The refinement of the other high-temperature structures was carried out by fixing the filling factors to those determined at RT, in order to avoid unwanted couplings with the displacement factors.

Temperature (K)	La occupancy (Phase 1)	La occupancy (Phase 2)
300	0.052(6)	0.33(2)
473	0.060(6)	0.36(2)
673	0.05(1)	0.35(2)
873	0.040(6)	0.34(2)
1073	0.054(7)	0.34(2)



Figure S6. Temperature dependence of the figure of merit, ZT, of $CoSb_3$ and three Sn-doped compositions, $Ce_{0.5}Co_4Sb_{12-y}Sn_{y.}$ The error bars are placed considering an error of ±15%.